





DMN3730UFB

30V N-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

V _{(BR)DSS}	R _{DS(on)}	Ι _D Τ _A = 25°C
30V	460mΩ @ V _{GS} = 4.5V	0.9A
307	560m Ω @ V _{GS} = 2.5V	0.7A

Description and Applications

This MOSFET has been designed to minimize the on-state resistance $(R_{DS(on)})$ and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

- Load switch
- Portable applications
- Power Management Functions

Features and Benefits

- 0.5mm ultra low profile package for thin application
- 0.6mm² package footprint, 10 times smaller than SOT23
- Low V_{GS(th)}, can be driven directly from a battery
- Low R_{DS(on)}
- "Lead Free", RoHS Compliant (Note 1)
- Halogen and Antimony Free. "Green" Device (Note 2)
- ESD Protected Gate 2kV
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

- Case: DFN1006-3
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020

NE = Product Type Marking Code

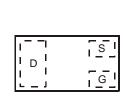
- Terminal Connections: See Diagram
- Terminals: Finish NiPdAu over Copper leadframe. Solderable per MIL-STD-202, Method 208
- Weight: 0.001 grams (approximate)

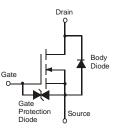




DFN1006-3

Bottom View





Top View Internal Schematic

Equivalent Circuit

Ordering Information (Note 3)

Part Number	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
DMN3730UFB-7	NE	7	8	3,000
DMN3730UFB-7B	NE	7	8	10,000

Notes: 1. No purposefully added lead

2. Diodes Inc's "Green" policy can be found on our website at http://www.diodes.com.

3. For packaging details, go to our website at http://www.diodes.com.

Marking Information

DMN3730UFB-7

Top View Dot Denotes Drain Side

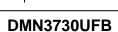
DMN3730UFB-7B



Top View Bar Denotes Gate and Source Side

DMN3730UFB Document number: DS35018 Rev. 3 - 2 Downloaded from <u>Elcodis.com</u> electronic components distributor 1 of 6 www.diodes.com





Maximum Ratings @T_A = 25°C unless otherwise specified

Characteristic		Symbol	Value	Unit	
Drain-Source Voltage			V _{DSS}	30	V
Gate-Source Voltage			V _{GSS}	±8	v
		(Note 5)		0.91	
Continuous Drain Current	$V_{GS} = 4.5V$	T _A =70°C (Note 5)	ID	0.73	А
		(Note 4)		0.75	
Pulsed Drain Current (Note 6)		I _{DM}	3	A	

Thermal Characteristics @T_A = 25°C unless otherwise specified

Characteristic		Symbol	Value	Unit	
Power Dissipation	(Note 5)	D	0.69	W	
	(Note 4)	PD	0.47	vv	
Thermal Resistance, Junction to Ambient	(Note 5)	Р	180	°C/W	
Thermal Resistance, Junction to Ambient	(Note 4)	R _{θJA}	258	C/W	
Operating and Storage Temperature Range		T _J , T _{STG}	-55 to +150	°C	

Electrical Characteristics @T_A = 25°C unless otherwise specified

				-	T		
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS							
Drain-Source Breakdown Voltage	BV _{DSS}	30	-	-	V	$V_{GS} = 0V, I_D = 10\mu A$	
Zero Gate Voltage Drain Current T _J = 25°C	I _{DSS}	-	-	1	μΑ	$V_{DS} = 30V, V_{GS} = 0V$	
Gate-Source Leakage	IGSS	-	-	3	μΑ	$V_{GS} = \pm 8V, V_{DS} = 0V$	
ON CHARACTERISTICS							
Gate Threshold Voltage	V _{GS(th)}	0.45	-	0.95	V	$V_{DS} = V_{GS}$, $I_D = 250 \mu A$	
				460		$V_{GS} = 4.5V, I_D = 200mA$	
Static Drain-Source On-Resistance (Note 7)	R _{DS (ON)}	-	-	560	mΩ	$V_{GS} = 2.5V, I_D = 100mA$	
				730		$V_{GS} = 1.8V, I_D = 75mA$	
Forward Transfer Admittance	Y _{fs}	40	-	-	mS	$V_{DS} = 3V, I_{D} = 10mA$	
Diode Forward Voltage (Note 7)	V _{SD}	-	0.7	1.2	V	$V_{GS} = 0V, I_{S} = 300mA$	
DYNAMIC CHARACTERISTICS (Note 8)						_	
Input Capacitance	C _{iss}	-	64.3	-	pF		
Output Capacitance	C _{oss}	-	6.1	-	pF	$-V_{DS} = 25V, V_{GS} = 0V,$ -f = 1.0MHz	
Reverse Transfer Capacitance	C _{rss}	-	4.5	-	pF		
Gate Resistance	R _g	-	70	-	Ω	$V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1MHz$	
Total Gate Charge	Qg	-	1.6	-	nC		
Gate-Source Charge	Q _{gs}	-	0.2	-	nC	− V _{GS} = 4.5V, V _{DS} = 15V, − I _D = 1A	
Gate-Drain Charge	Q _{gd}	-	0.2	-	nC	ID = IA	
Turn-On Delay Time	t _{D(on)}	-	3.5	-	ns		
Turn-On Rise Time	tr	-	2.8	-	ns	$V_{DS} = 10V, I_D = 1A$	
Turn-Off Delay Time	t _{D(off)}	-	38	-	ns	V_{GS} = 10V, R_G = 6 Ω	
Turn-Off Fall Time	t _f	-	13	-	ns		

4. For a device surface mounted on a minimum recommended pad layout of an FR4 PCB, in still air conditions; the device is measured when operating in steady-state condition.

5. Same as note 4, except the device measured at t \leq 10 sec.

6. Same as note 4, except the device is pulsed at duty cycle of 1% for a pulse width of 10 μ s. 7. Measured under pulsed conditions to minimize self-heating effect. Pulse width \leq 300 μ s; duty cycle \leq 2%

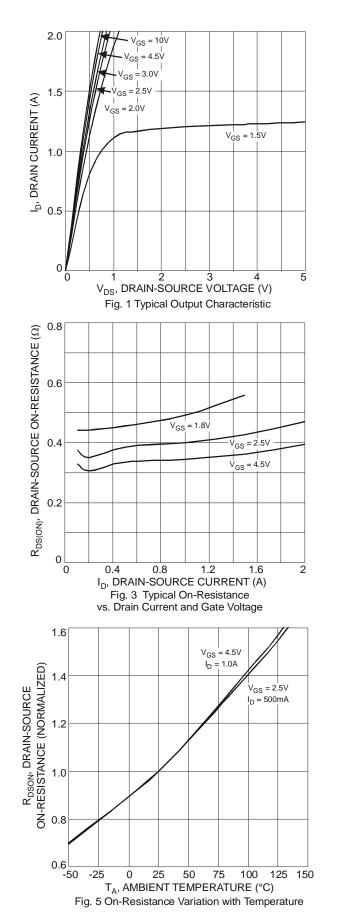
8. For design aid only, not subject to production testing.

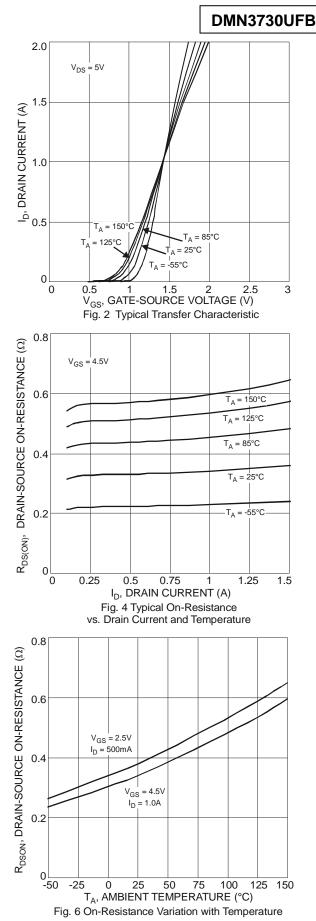
Notes:



A Product Line of Diodes Incorporated



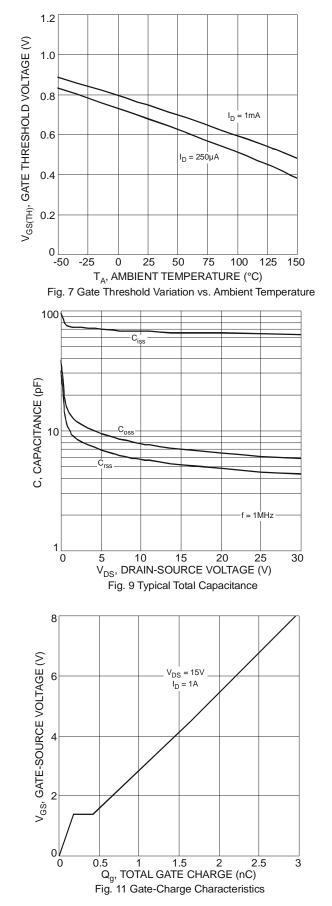


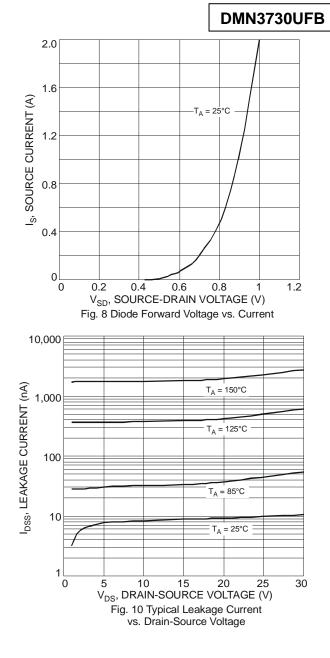




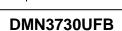
A Product Line of Diodes Incorporated

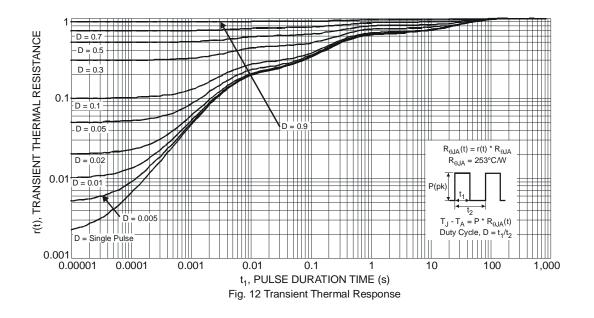




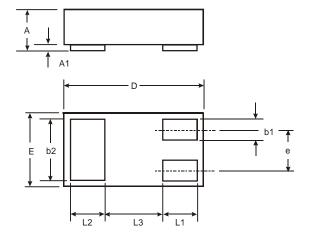






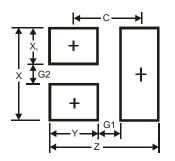


Package Outline Dimensions



DFN1006-3					
Dim	Min	Max	Тур		
Α	0.47	0.53	0.50		
A1	0	0.05	0.03		
b1	0.10	0.20	0.15		
b2	0.45	0.55	0.50		
D	0.95	1.075	1.00		
Ε	0.55	0.675	0.60		
е			0.35		
L1 0.20		0.30	0.25		
L2	0.20	0.30	0.25		
L3	-	_	0.40		
All Dimensions in mm					

Suggested Pad Layout



Dimensions	Value (in mm)
Z	1.1
G1	0.3
G2	0.2
Х	0.7
X1	0.25
Y	0.4
С	0.7

DMN3730UFB Document number: DS35018 Rev. 3 - 2 Downloaded from <u>Elcodis.com</u> electronic components distributor



DMN3730UFB

IMPORTANT NOTICE

DIODES INCORPORATED MAKES NO WARRANTY OF ANY KIND, EXPRESS OR IMPLIED, WITH REGARDS TO THIS DOCUMENT, INCLUDING, BUT NOT LIMITED TO, THE IMPLIED WARRANTIES OF MERCHANTABILITY AND FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION).

Diodes Incorporated and its subsidiaries reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to this document and any product described herein. Diodes Incorporated does not assume any liability arising out of the application or use of this document or any product described herein; neither does Diodes Incorporated convey any license under its patent or trademark rights, nor the rights of others. Any Customer or user of this document or products described herein in such applications shall assume all risks of such use and will agree to hold Diodes Incorporated and all the companies whose products are represented on Diodes Incorporated website, harmless against all damages.

Diodes Incorporated does not warrant or accept any liability whatsoever in respect of any products purchased through unauthorized sales channel. Should Customers purchase or use Diodes Incorporated products for any unintended or unauthorized application, Customers shall indemnify and hold Diodes Incorporated and its representatives harmless against all claims, damages, expenses, and attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized application.

Products described herein may be covered by one or more United States, international or foreign patents pending. Product names and markings noted herein may also be covered by one or more United States, international or foreign trademarks.

LIFE SUPPORT

Diodes Incorporated products are specifically not authorized for use as critical components in life support devices or systems without the express written approval of the Chief Executive Officer of Diodes Incorporated. As used herein:

- A. Life support devices or systems are devices or systems which:
 - 1. are intended to implant into the body, or
 - 2. support or sustain life and whose failure to perform when properly used in accordance with instructions for use provided in the labeling can be reasonably expected to result in significant injury to the user.
- B. A critical component is any component in a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or to affect its safety or effectiveness.

Customers represent that they have all necessary expertise in the safety and regulatory ramifications of their life support devices or systems, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of Diodes Incorporated products in such safety-critical, life support devices or systems, notwithstanding any devices- or systems-related information or support that may be provided by Diodes Incorporated. Further, Customers must fully indemnify Diodes Incorporated and its representatives against any damages arising out of the use of Diodes Incorporated products in such safety-critical, life support devices or systems.

Copyright © 2011, Diodes Incorporated

www.diodes.com